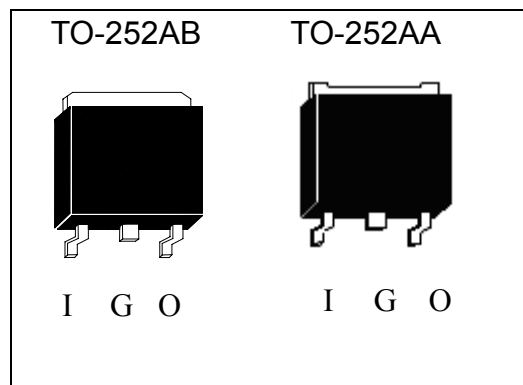


Three Terminal Positive Voltage Regulators

LM78XXJ3



Description

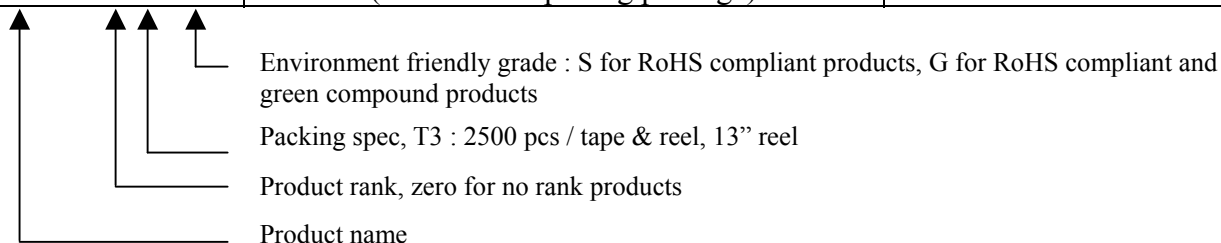
The LM78XXJ3 series of fixed voltage monolithic integrated circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single point regulation. Each of these regulators can deliver up to 1A of output current. The internal current limiting and thermal shutdown features of these regulators make them essentially immune to overload.

Features:

- 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V, 24V output voltage available
- Internal Short-Circuit Current Limiting
- High Power Dissipation Capability
- Internal Thermal Overload Protection
- No External Components Required
- Output Transistor Safe Area Compensation
- Pb-free lead plating package

Ordering Information

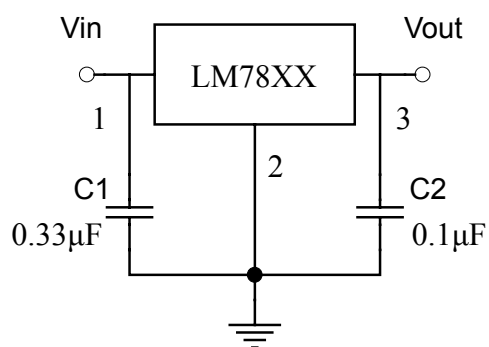
Device	Package	Shipping
LM78XXJ3-X-T3-X	TO-252 (Pb-free lead plating package)	2500 pcs / Tape & Reel



Absolute Maximum Ratings (Ta=25°C)

Parameter		Ratings	Unit
Input Voltage	LM7805~LM7818	35	V
	LM7824	40	
Output Current		1	A
Operating Junction Temperature Range		-40 ~ +125	°C
Storage Temperature Range		-55 ~ +125	°C
Thermal Resistance, Junction to Ambient (R θ JA)		125	°C/W
Thermal Resistance, Junction to Case (R θ JC)		12.5	°C/W

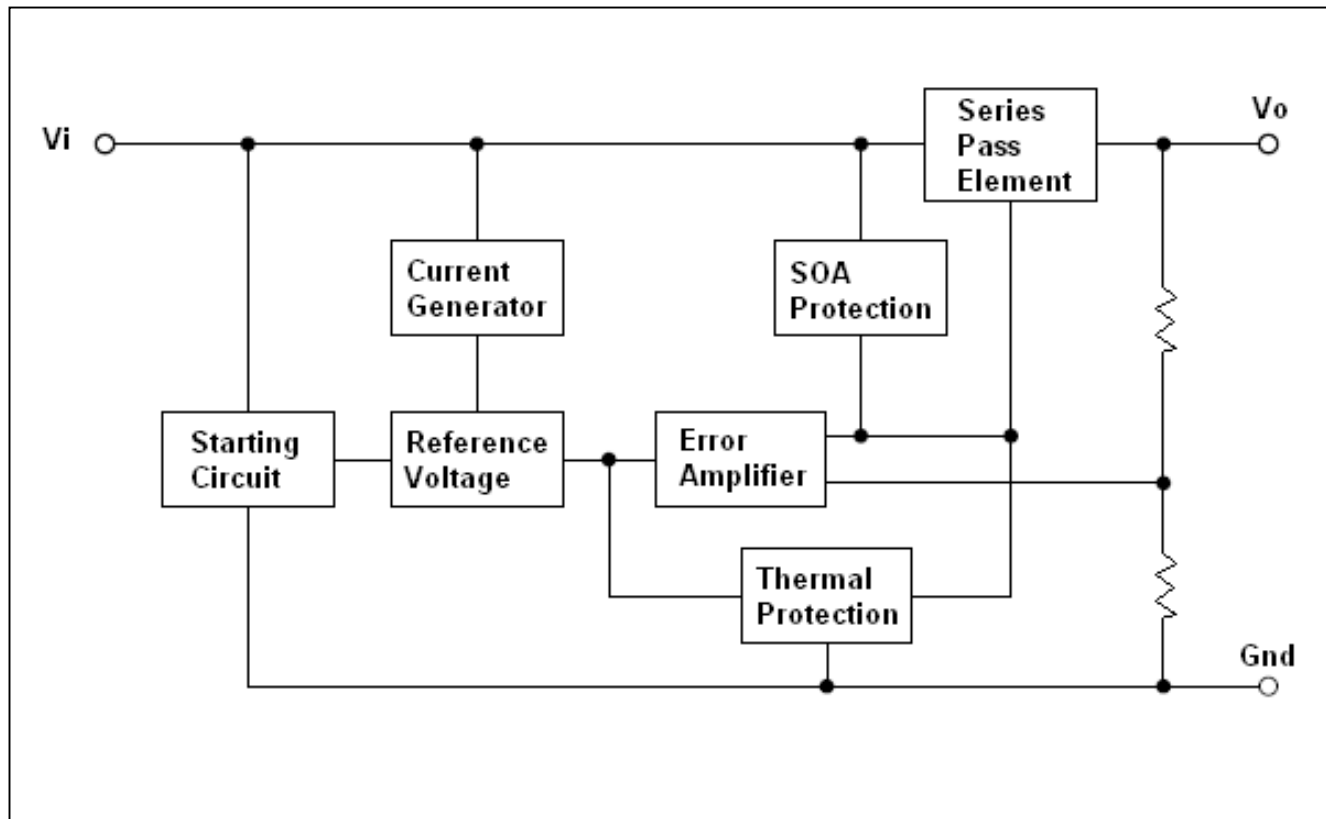
Typical Application Circuit



Note:

C1 and C2 are required if regulator is located far from power supply filter and load, or oscillation may induced on the loop.

Block Diagram



Electrical Characteristics

LM7805 ($T_j=0\sim125^{\circ}\text{C}$, $V_{in}=10\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	Output Voltage	4.85	5.0	5.15	$V_{in}=10\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	V
		4.75	-	5.25	$7.5\text{V}\leq V_{in}\leq 20\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $P_D\leq 15\text{W}$	
ΔV_o	Line Regulation	-	3	50	$7\text{V}\leq V_{in}\leq 25\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	1	25	$8\text{V}\leq V_{in}\leq 12\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	100	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=10\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.3	$7\text{V}\leq V_{in}\leq 25\text{V}$	
V_n	Output Noise Voltage	-	40	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	80	-	$8\text{V}\leq V_{in}\leq 18\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-0.6	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

**LM7806** ($T_j=0\sim125^{\circ}\text{C}$, $V_{in}=11\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	5.82	6.0	6.18	$V_{in}=11\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $8\text{V}\leq V_{in}\leq 21\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $PD\leq 15\text{W}$	V
	B-rank(5%)	5.70	-	6.30		
ΔV_o	Line Regulation	-	3	60	$8\text{V}\leq V_{in}\leq 25\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	1	25	$9\text{V}\leq V_{in}\leq 13\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	100	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=11\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.3	$8\text{V}\leq V_{in}\leq 25\text{V}$	
V_n	Output Noise Voltage	-	45	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	75	-	$9\text{V}\leq V_{in}\leq 19\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-0.7	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

LM7808 ($T_j=0\sim125^{\circ}\text{C}$, $V_{in}=14\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	7.76	8.0	8.24	$V_{in}=14\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $10.5\text{V}\leq V_{in}\leq 23\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $PD\leq 15\text{W}$	V
	B-rank(5%)	7.60	-	8.40		
ΔV_o	Line Regulation	-	3	80	$10.5\text{V}\leq V_{in}\leq 25\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	1	40	$11\text{V}\leq V_{in}\leq 17\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	100	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=14\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.3	$10.5\text{V}\leq V_{in}\leq 25\text{V}$	
V_n	Output Noise Voltage	-	58	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	72	-	$11.5\text{V}\leq V_{in}\leq 21.5\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-0.9	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$


LM7809 ($T_j=0\sim125^{\circ}\text{C}$, $V_{in}=15\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	8.73	9.0	9.27	$V_{in}=15\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $11.5\text{V}\leq V_{in}\leq 24\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $P_D\leq 15\text{W}$	V
	B-rank(5%)	8.55	-	9.45		
ΔV_o	Line Regulation	-	5	90	$11.5\text{V}\leq V_{in}\leq 25\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	3	45	$13\text{V}\leq V_{in}\leq 19\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	100	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=15\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.3	$11.5\text{V}\leq V_{in}\leq 26\text{V}$	
V_n	Output Noise Voltage	-	58	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	72	-	$12.5\text{V}\leq V_{in}\leq 22.5\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-1.1	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

LM7810 ($T_j=0\sim125^{\circ}\text{C}$, $V_{in}=16\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	9.70	10.0	10.30	$V_{in}=16\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $12.5\text{V}\leq V_{in}\leq 25\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $P_D\leq 15\text{W}$	V
	B-rank(5%)	9.50	-	10.50		
ΔV_o	Line Regulation	-	-	100	$13\text{V}\leq V_{in}\leq 25\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$14\text{V}\leq V_{in}\leq 20\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	100	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	50	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=16\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.0	$12.5\text{V}\leq V_{in}\leq 25\text{V}$	
V_n	Output Noise Voltage	-	58	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	72	-	$13\text{V}\leq V_{in}\leq 23\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-1.1	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

**LM7812** (Tj=0~125°C, Vin=19V, Io=500mA, Cin=0.33uF, Cout=0.1uF, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
Vo	A-rank(3%)	11.64	12.0	12.36	Vin=19V, Io=500mA, Tj=25°C 14.5V≤Vin≤27V, 5mA≤Io≤1A, PD≤15W	V
	B-rank(5%)	11.40	-	12.60		
ΔVo	Line Regulation	-	10	120	14.5V≤Vin≤30V, Tj=25°C	mV
		-	3	60	16V≤Vin≤22V, Tj=25°C	
ΔVo	Load Regulation	-	-	100	5mA≤Io≤1A, Tj=25°C	mV
		-	-	60	250mA≤Io≤750mA, Tj=25°C	
IQ	Quiescent Current	-	-	8	Vin=19V, Io=500mA, Tj=25°C	mA
ΔIQ	Quiescent Current Change	-	-	0.5	5mA≤Io≤1A	mA
		-	-	1.3	14.5V≤Vin≤30V	
Vn	Output Noise Voltage	-	75	-	10Hz≤f≤100KHz, Tj=25°C	μV
RR	Ripple Rejection	-	72	-	15V≤Vin≤25V, f=120Hz, Tj=25°C	dB
VD	Dropout Voltage	-	2	-	Io=1A, Tj=25°C	V
ISC	Output Short Circuit Current	-	250	-	Vin=35V, Tj=25°C	mA
IPK	Peak Output Current	-	1.8	-	Tj=25°C	A
ΔVo/ΔTj	Temperature Stability	-	-1.5	-	Io=5mA, 0°C≤Tj≤125°C	mV/°C

LM7815 (Tj=0~125°C, Vin=23V, Io=500mA, Cin=0.33uF, Cout=0.1uF, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
Vo	A-rank(3%)	14.55	15.0	15.45	Vin=23V, Io=500mA, Tj=25°C 17.5V≤Vin≤30V, 5mA≤Io≤1A, PD≤15W	V
	B-rank(5%)	14.25	-	15.75		
ΔVo	Line Regulation	-	-	150	17.5V≤Vin≤30V, Tj=25°C	mV
		-	-	75	18.5V≤Vin≤30V, Tj=25°C	
ΔVo	Load Regulation	-	-	150	5mA≤Io≤1A, Tj=25°C	mV
		-	-	75	250mA≤Io≤750mA, Tj=25°C	
IQ	Quiescent Current	-	-	8	Vin=23V, Io=500mA, Tj=25°C	mA
ΔIQ	Quiescent Current Change	-	-	0.5	5mA≤Io≤1A	mA
		-	-	1.3	17.5V≤Vin≤30V	
Vn	Output Noise Voltage	-	90	-	10Hz≤f≤100KHz, Tj=25°C	μV
RR	Ripple Rejection	-	70	-	18.5V≤Vin≤28.5V, f=120Hz, Tj=25°C	dB
VD	Dropout Voltage	-	2	-	Io=1A, Tj=25°C	V
ISC	Output Short Circuit Current	-	250	-	Vin=35V, Tj=25°C	mA
IPK	Peak Output Current	-	1.8	-	Tj=25°C	A
ΔVo/ΔTj	Temperature Stability	-	-1.8	-	Io=5mA, 0°C≤Tj≤125°C	mV/°C

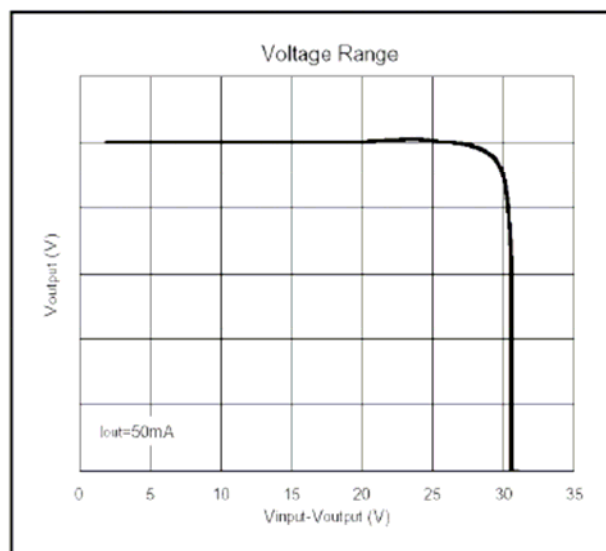
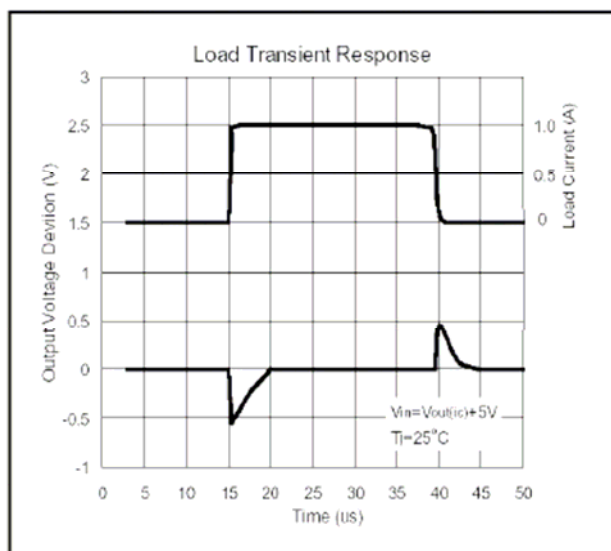
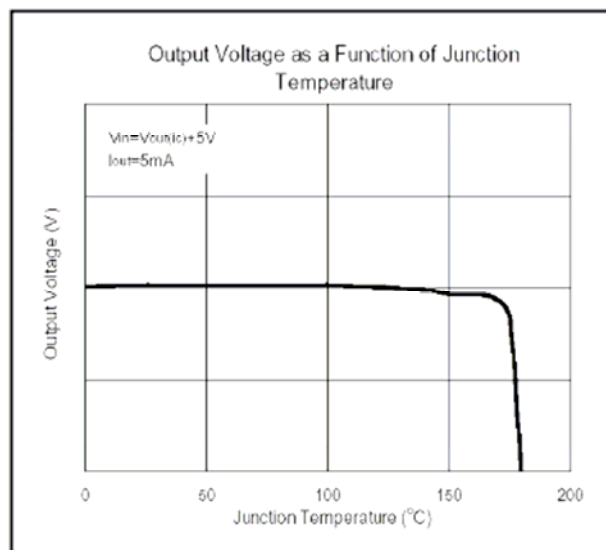
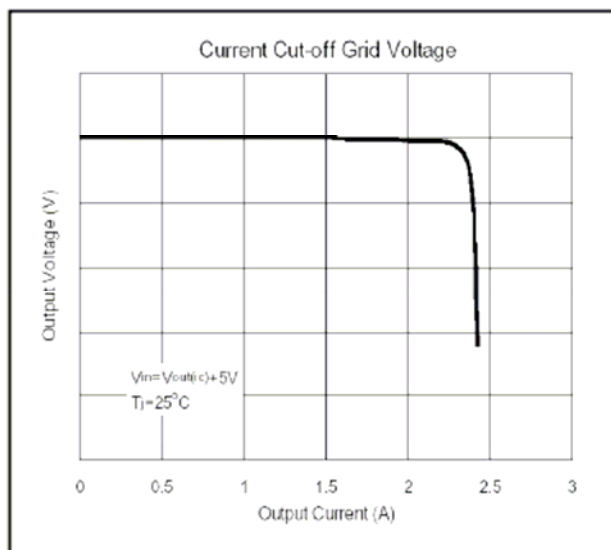

LM7818 ($T_j=0\sim 125^{\circ}\text{C}$, $V_{in}=27\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	17.46	18.0	18.54	$V_{in}=27\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $21\text{V}\leq V_{in}\leq 33\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $PD\leq 15\text{W}$	V
	B-rank(5%)	17.10	-	18.90		
ΔV_o	Line Regulation	-	-	180	$21\text{V}\leq V_{in}\leq 33\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	90	$24\text{V}\leq V_{in}\leq 30\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	180	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	90	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=27\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.0	$21\text{V}\leq V_{in}\leq 33\text{V}$	
V_n	Output Noise Voltage	-	110	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	69	-	$22\text{V}\leq V_{in}\leq 32\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-2.2	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

LM7824 ($T_j=0\sim 125^{\circ}\text{C}$, $V_{in}=33\text{V}$, $I_o=500\text{mA}$, $C_{in}=0.33\mu\text{F}$, $C_{out}=0.1\mu\text{F}$, unless otherwise noted)

Symbol	Parameter	Min	Typ	Max	Conditions	Units
V_o	A-rank(3%)	23.28	24.0	24.72	$V_{in}=33\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$ $27\text{V}\leq V_{in}\leq 38\text{V}$, $5\text{mA}\leq I_o\leq 1\text{A}$, $PD\leq 15\text{W}$	V
	B-rank(5%)	22.80	-	25.20		
ΔV_o	Line Regulation	-	-	240	$27\text{V}\leq V_{in}\leq 38\text{V}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	120	$30\text{V}\leq V_{in}\leq 36\text{V}$, $T_j=25^{\circ}\text{C}$	
ΔV_o	Load Regulation	-	-	240	$5\text{mA}\leq I_o\leq 1\text{A}$, $T_j=25^{\circ}\text{C}$	mV
		-	-	120	$250\text{mA}\leq I_o\leq 750\text{mA}$, $T_j=25^{\circ}\text{C}$	
I_Q	Quiescent Current	-	-	8	$V_{in}=33\text{V}$, $I_o=500\text{mA}$, $T_j=25^{\circ}\text{C}$	mA
ΔI_Q	Quiescent Current Change	-	-	0.5	$5\text{mA}\leq I_o\leq 1\text{A}$	mA
		-	-	1.0	$28\text{V}\leq V_{in}\leq 38\text{V}$	
V_n	Output Noise Voltage	-	170	-	$10\text{Hz}\leq f\leq 100\text{KHz}$, $T_j=25^{\circ}\text{C}$	μV
RR	Ripple Rejection	-	66	-	$28\text{V}\leq V_{in}\leq 38\text{V}$, $f=120\text{Hz}$, $T_j=25^{\circ}\text{C}$	dB
VD	Dropout Voltage	-	2	-	$I_o=1\text{A}$, $T_j=25^{\circ}\text{C}$	V
ISC	Output Short Circuit Current	-	250	-	$V_{in}=35\text{V}$, $T_j=25^{\circ}\text{C}$	mA
IPK	Peak Output Current	-	1.8	-	$T_j=25^{\circ}\text{C}$	A
$\Delta V_o/\Delta T_j$	Temperature Stability	-	-2.8	-	$I_o=5\text{mA}$, $0^{\circ}\text{C}\leq T_j\leq 125^{\circ}\text{C}$	$\text{mV}/^{\circ}\text{C}$

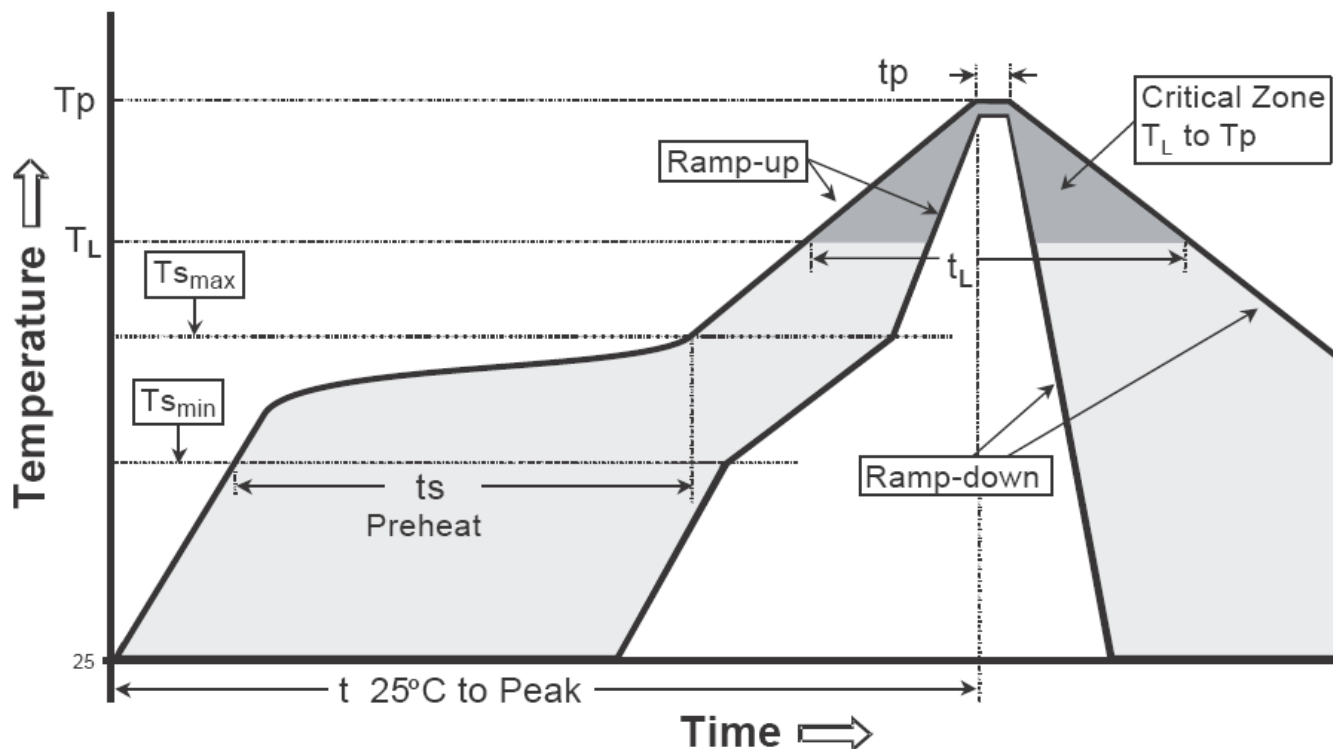
Characteristic Curves



Recommended wave soldering condition

Product	Peak Temperature	Soldering Time
Pb-free devices	260 +0/-5 °C	5 +1/-1 seconds

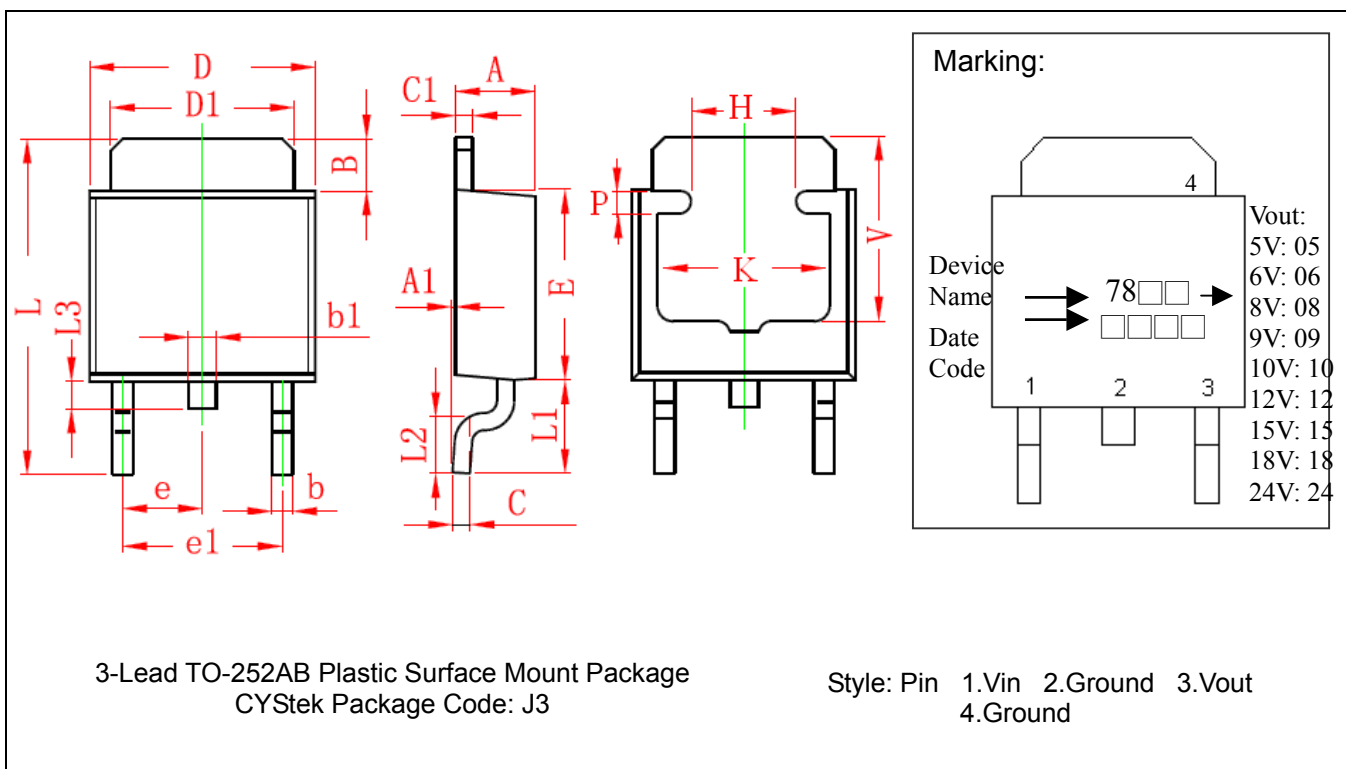
Recommended temperature profile for IR reflow



Profile feature	Sn-Pb eutectic Assembly	Pb-free Assembly
Average ramp-up rate (T_{smax} to T_p)	3°C/second max.	3°C/second max.
Preheat -Temperature Min(T_{smin}) -Temperature Max(T_{smax}) -Time(t_{smin} to t_{smax})	100°C 150°C 60-120 seconds	150°C 200°C 60-180 seconds
Time maintained above: -Temperature (T_L) - Time (t_L)	183°C 60-150 seconds	217°C 60-150 seconds
Peak Temperature(T_p)	240 +0/-5 °C	260 +0/-5 °C
Time within 5°C of actual peak temperature(t_p)	10-30 seconds	20-40 seconds
Ramp down rate	6°C/second max.	6°C/second max.
Time 25 °C to peak temperature	6 minutes max.	8 minutes max.

Note : All temperatures refer to topside of the package, measured on the package body surface.

TO-252AB Dimension



*: Typical

DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	e	*0.091		*2.300	
A1	0.000	0.005	0.000	0.127	e1	0.177	0.185	4.500	4.700
B	0.053	0.065	1.350	1.650	H	0.118	REF	3.000	REF
b	0.020	0.028	0.500	0.700	K	0.197	REF	5.000	REF
b1	0.028	0.035	0.700	0.900	L	0.374	0.390	9.500	9.900
C	0.017	0.023	0.430	0.580	L1	0.100	0.114	2.550	2.900
C1	0.017	0.023	0.430	0.580	L2	0.055	0.070	1.400	1.780
D	0.250	0.262	6.350	6.650	L3	0.024	0.035	0.600	0.900
D1	0.205	0.213	5.200	5.400	P	0.028	REF	0.700	REF
E	0.213	0.224	5.400	5.700	V	0.209	REF	5.300	REF

Notes: 1.Controlling dimension: millimeters.

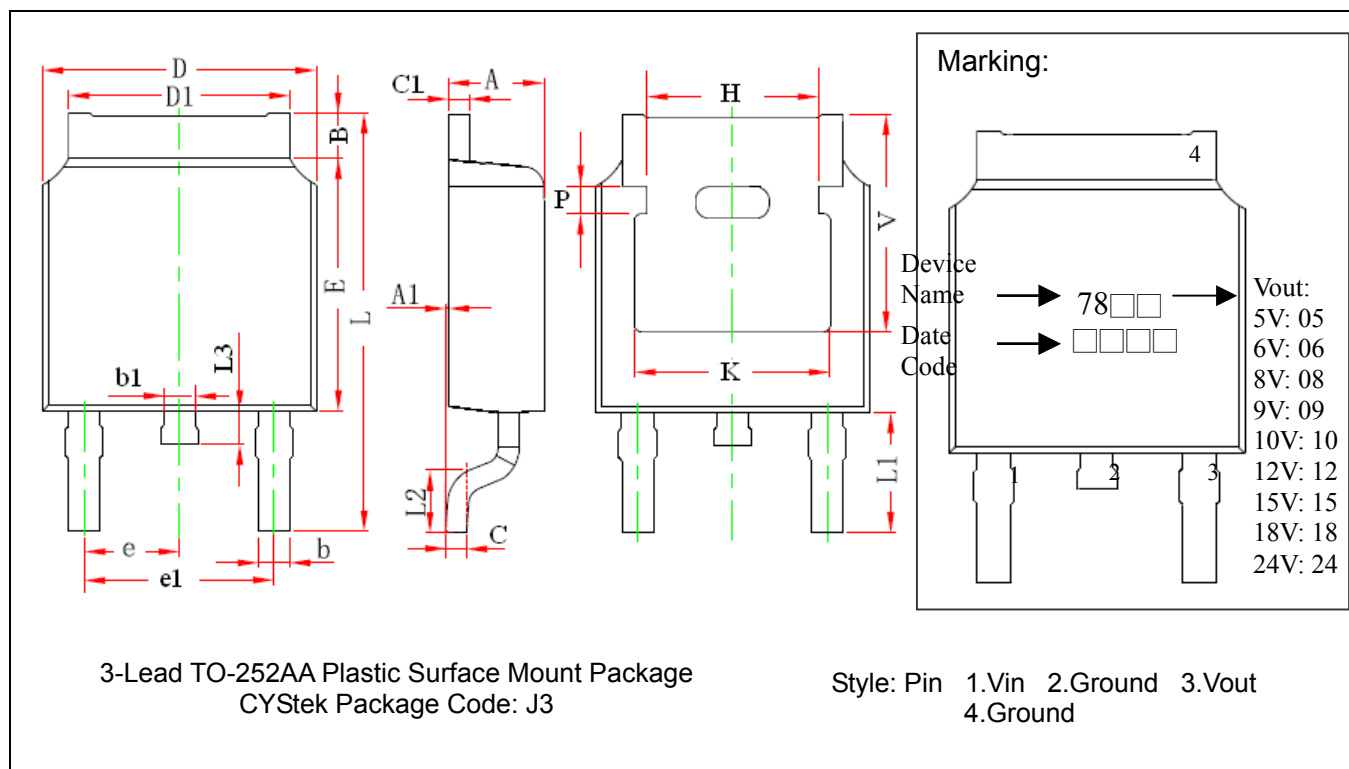
2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead : Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

TO-252AA Dimension



DIM	Inches		Millimeters		DIM	Inches		Millimeters	
	Min.	Max.	Min.	Max.		Min.	Max.	Min.	Max.
A	0.087	0.094	2.200	2.400	e	0.086	0.094	2.186	2.386
A1	0.000	0.005	0.000	0.127	e1	0.172	0.188	4.372	4.772
B	0.039	0.048	0.990	1.210	H	0.163	REF	4.140	REF
b	0.026	0.034	0.660	0.860	K	0.190	REF	4.830	REF
b1	0.026	0.034	0.660	0.860	L	0.386	0.409	9.800	10.400
C	0.018	0.023	0.460	0.580	L1	0.114	REF	2.900	REF
C1	0.018	0.023	0.460	0.580	L2	0.055	0.067	1.400	1.700
D	0.256	0.264	6.500	6.700	L3	0.024	0.039	0.600	1.000
D1	0.201	0.215	5.100	5.460	P	0.026	REF	0.650	REF
E	0.236	0.244	6.000	6.200	V	0.211	REF	5.350	REF

Notes: 1.Controlling dimension: millimeters.

2.Maximum lead thickness includes lead finish thickness, and minimum lead thickness is the minimum thickness of base material.

3.If there is any question with packing specification or packing method, please contact your local CYStek sales office.

Material:

- Lead : Pure tin plated.
- Mold Compound: Epoxy resin family, flammability solid burning class: UL94V-0.

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